

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Dominik EISERT et al.

Serial No.: 10/523,551

Filed: October 18, 2005

For: GaN-Based Radiation-Emitting Thin-Layered
Semiconductor Component

Examiner: Nguyen, Joseph H.
Group Art: 2815

Confirmation #:1182

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

S I R:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56 and in accordance with the practice under 37 C.F.R. §§ 1.97 and 1.98, the Examiner's attention is directed to the documents listed on the enclosed form PTO/SB/08A. Copies of the listed documents are also enclosed.

Also enclosed is an English translation of a Japanese Examination Report issued by the Japanese Patent Office on April 30, 2009 in a corresponding Japanese application

This information is being submitted after issuance of a Notice of Allowance, but before payment of the Issue Fee.

In accordance with 37 C.F.R §§1.97(g) and (h), the filing of this Information Disclosure Statement should not be construed as a representation that a search has been made or that information cited is, or is considered to be, material to patentability as defined in §1.56(b),

or that any cited document listed or attached is (or constitutes) prior art. Unless otherwise indicated, the date of publication indicated for an item is taken from the face of the item and Applicant(s) reserve(s) the right to prove that the date of publication is in fact different.

It is respectfully requested that the above information be considered by the Examiner and that a copy of the enclosed form PTO/SB/08A be returned indicating that such information has been considered.

Respectfully submitted,
COHEN PONTANI LIEBERMAN & PAVANE LLP

By /Thomas Langer/
Thomas Langer
Reg. No. 27,264
551 Fifth Avenue, Suite 1210
New York, New York 10176
(212) 687-2770

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